

# **Excellent Integrated System Limited**

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<u>Vishay Semiconductor/Diodes Division</u> <u>VBT6045C-M3/8W</u>

For any questions, you can email us directly: <a href="mailto:sales@integrated-circuit.com">sales@integrated-circuit.com</a>

### Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VBT6045C-M3/8W - DIODE SCHOTTKY 60A 45V TO-263AB

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### VBT6045C-M3

Vishay General Semiconductor

# **Dual Low-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.33 \text{ V}$  at  $I_F = 10 \text{ A}$ 

TMBS® TO-263AB

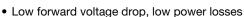


1
VBT6045C
PIN 1 O
PIN 2 O HEATSINK

PRIMARY CHARACTERISTICS				
Package	TO-263AB			
I <sub>F(AV)</sub>	2 x 30 A			
V <sub>RRM</sub>	45 V			
I <sub>FSM</sub>	320 A			
V <sub>F</sub> at I <sub>F</sub> = 30 A	0.47 V			
T <sub>J</sub> max.	150 °C			
Diode variation	Common cathode			

#### **FEATURES**

· Trench MOS Schottky technology



COMPLIANT

· High efficiency operation

• Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C

FREE

• Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

### **MECHANICAL DATA**

Case: TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VBT6045C	UNIT	
Maximum repetitive peak reverse voltage		$V_{RRM}$	45	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	60	А	
	per diode		30		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	320	А	
Operating junction and storage temperature range		$T_J$ , $T_{STG}$	- 40 to + 150	°C	

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### **VBT6045C-M3**

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 10 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.44	-	V
	I <sub>F</sub> = 15 A			0.47	-	
	I <sub>F</sub> = 30 A			0.54	0.64	
	I <sub>F</sub> = 10 A	T <sub>A</sub> = 125 °C		0.33	-	
	I <sub>F</sub> = 15 A			0.37	-	
	I <sub>F</sub> = 30 A			0.47	0.56	
Reverse current per diode	$V_{R} = 45 \text{ V}$	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	3000	μΑ
	$V_R = 45 \text{ V}$ $T_A = 125 ^\circ$	T <sub>A</sub> = 125 °C		18	50	mA

#### Notes

- (1) Pulse test: 300 µs pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER		SYMBOL	VBT64045C	UNIT
Typical thermal resistance	per diode	$R_{ heta JC}$	1.5	°C/W
	per device		0.8	

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-263AB	VBT6045C-M3/4W	1.38	4W	50/tube	Tube			
TO-263AB	VBT6045C-M3/8W	1.38	8W	800/reel	Tape and reel			

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

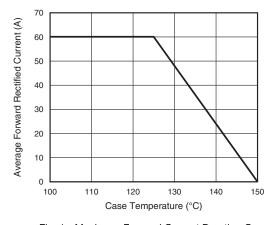


Fig. 1 - Maximum Forward Current Derating Curve

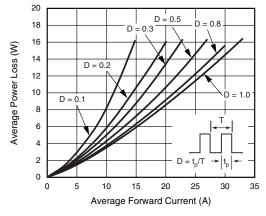


Fig. 2 - Forward Power Loss Characteristics Per Diode

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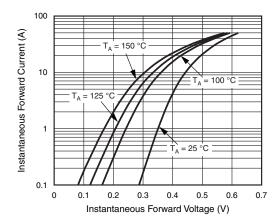


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

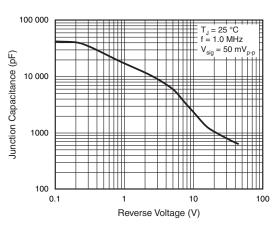


Fig. 5 - Typical Junction Capacitance Per Diode

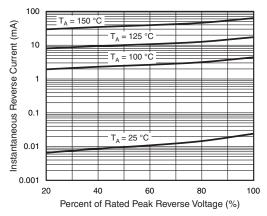


Fig. 4 - Typical Reverse Characteristics Per Diode

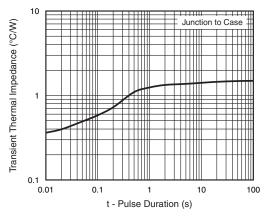
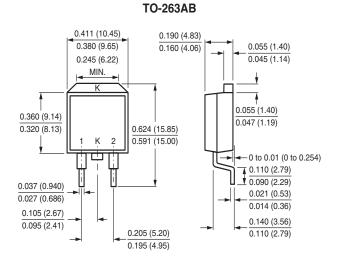
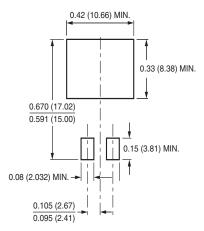


Fig. 6 - Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



### **Mounting Pad Layout**



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